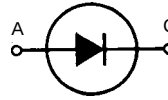


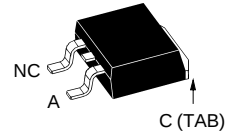
Fast Recovery Epitaxial Diode (FRED)

DSEI 8 $I_{FAVM} = 8\text{ A}$
 $V_{RRM} = 600\text{ V}$
 $t_{rr} = 35\text{ ns}$

V_{RSM} V	V_{RRM} V	Type
640	600	DSEI 8-06A
640	600	DSEI 8-06AS

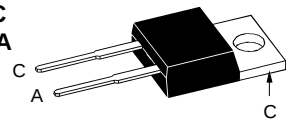


TO-263 AA
DSEI 8-06AS



Symbol	Test Conditions	Maximum Ratings	
I_{FRMS} I_{FAVM} ① I_{FRM}	$T_{VJ} = T_{VJM}$ $T_C = 115^\circ\text{C}$; rectangular, $d = 0.5$ $t_p < 10\text{ }\mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	16 8 130	A A A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine	100 110	A A
	$T_{VJ} = 150^\circ\text{C}$; $t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine	85 95	A A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine	50 50	A^2s A^2s
	$T_{VJ} = 150^\circ\text{C}$; $t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine	36 37	A^2s A^2s
T_{VJ} T_{VJM} T_{stg}		-40...+150 150 -40...+150	$^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C}$
P_{tot}	$T_C = 25^\circ\text{C}$	50	W
M_d	Mounting torque	0.4...0.6	Nm
Weight		2	g

TO-220 AC
DSEI 8-06A



A = Anode, C = Cathode, NC = No connection
TAB = Cathode

Features

- International standard package JEDEC TO-220 AC & TO-263 AB
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Symbol	Test Conditions	Characteristic Values	
		typ.	max.
I_R	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	20 10 1.5	μA μA mA
V_F	$I_F = 8\text{ A}$; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	1.3 1.5	V V
V_{T0} r_T	For power-loss calculations only $T_{VJ} = T_{VJM}$	0.98 28.7	V m Ω
R_{thJC} R_{thCK} R_{thJA}	0.5	2.5 60	K/W K/W K/W
t_{rr}	$I_F = 1\text{ A}$; $-di/dt = 50\text{ A}/\mu\text{s}$; $V_R = 30\text{ V}$; $T_{VJ} = 25^\circ\text{C}$	35	50 ns
I_{RM}	$V_R = 350\text{ V}$; $I_F = 8\text{ A}$; $-di_F/dt = 64\text{ A}/\mu\text{s}$ $L \leq 0.05\text{ }\mu\text{H}$; $T_{VJ} = 100^\circ\text{C}$	2.5	2.8 A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$
 Data according to IEC 60747
 IXYS reserves the right to change limits, test conditions and dimensions

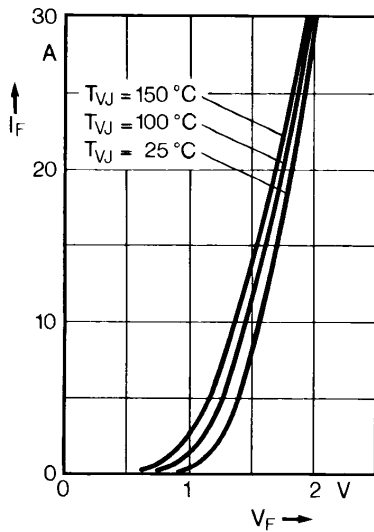


Fig. 1 Forward current versus voltage drop.

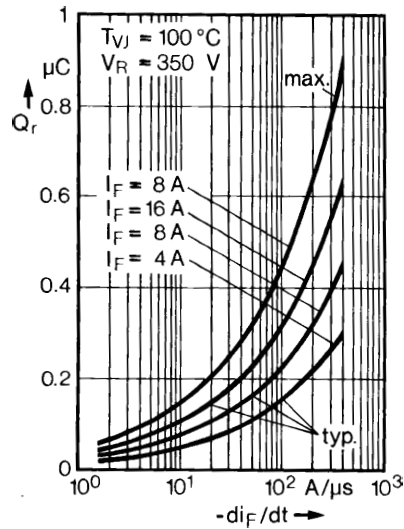


Fig. 2 Recovery charge versus $-di_F/dt$.

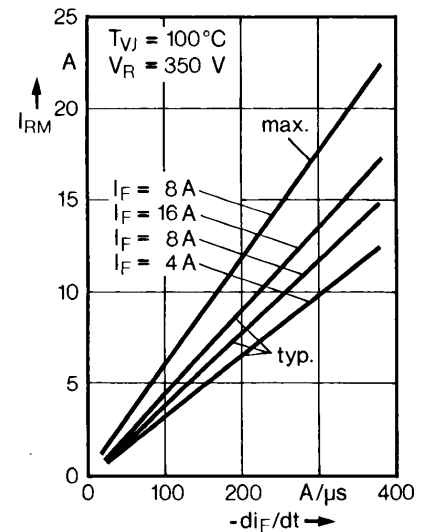


Fig. 3 Peak reverse current versus $-di_F/dt$.

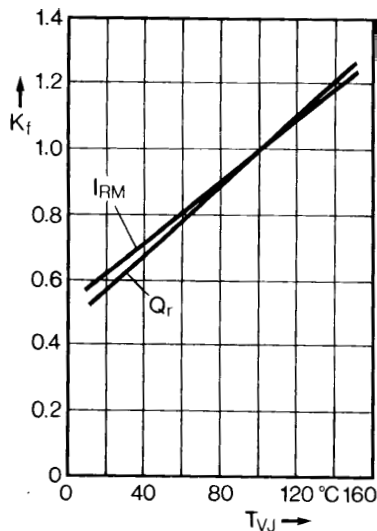


Fig. 4 Dynamic parameters versus junction temperature.

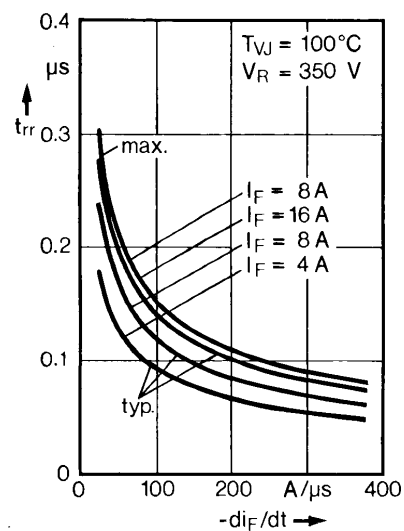


Fig. 5 Recovery time versus $-di_F/dt$.

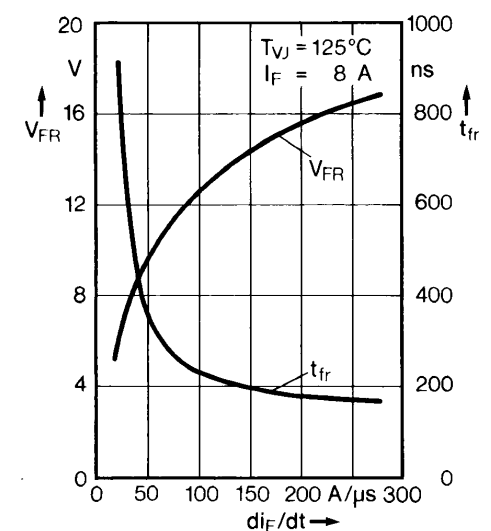


Fig. 6 Peak forward voltage versus di_F/dt .

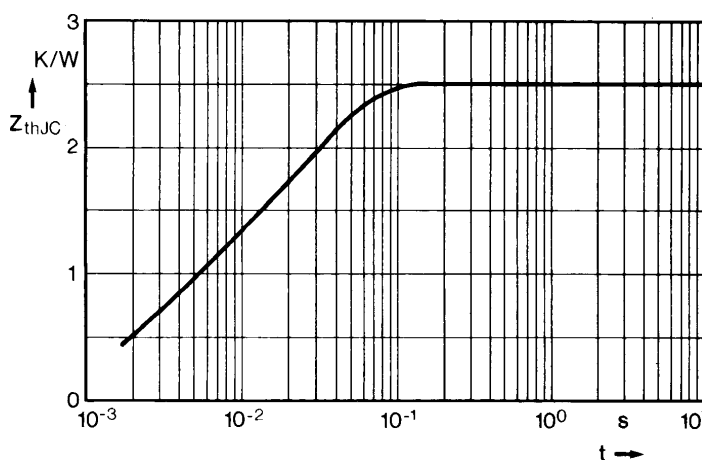
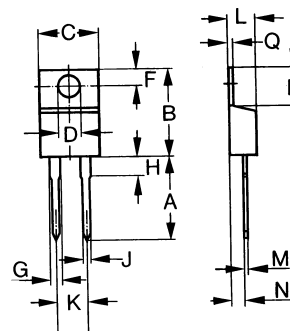


Fig. 7 Transient thermal impedance junction to case.

Dimensions TO-220 AC



Dim.	Millimeter	Inches
	Min. Max.	Min. Max.
A	12.70 14.73	0.500 0.580
B	14.23 16.51	0.560 0.650
C	9.66 10.66	0.380 0.420
D	3.54 4.08	0.139 0.161
E	5.85 6.85	0.230 0.420
F	2.54 3.42	0.100 0.135
G	1.15 1.77	0.045 0.070
H	- 6.35	- 0.250
J	0.64 0.89	0.025 0.035
K	4.83 5.33	0.190 0.210
L	3.56 4.82	0.140 0.190
M	0.38 0.56	0.015 0.022
N	2.04 2.49	0.080 0.115
Q	0.64 1.39	0.025 0.055

Dimension TO-263 AA see DSEI 19